

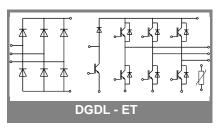
3-phase bridge rectifier + brake chopper + 3-phase bridge inverter SK 15 DGDL 12T4 ET

Target Data

#### **Features**

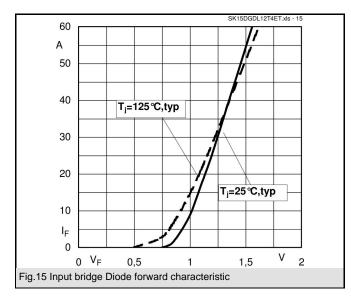
- One screw mounting module
- Trench4 IGBT technology
- CAL4 technology FWD
- Integrated NTC temperature sensor

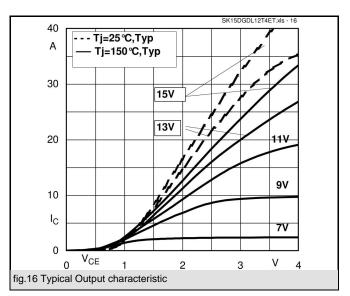
1)  $V_{CE,sat}$ ,  $V_F$  = chip level value

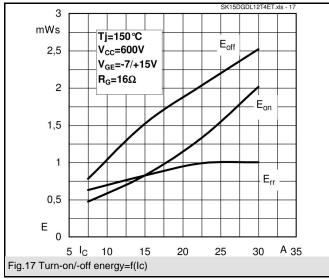


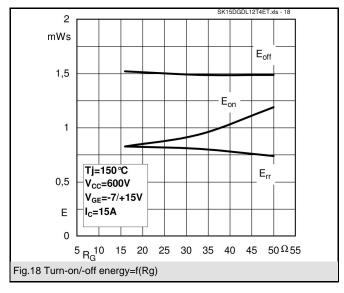
Absolute Maximum Ratings Ts = 25 °C, unless otherwise specific							
Symbol	Conditions	Values	Units				
IGBT - Inverter,Chopper							
$V_{CES}$		1200	V				
I <sub>C</sub>	T <sub>s</sub> = 25 (70) °C	27 (21)	Α				
I <sub>CRM</sub>	$I_{CRM}$ = 3 x $I_{Cnom}$ , $t_p$ = 1 ms	45	Α				
$V_{GES}$		± 20	V				
T <sub>j</sub>		-40 <b>+</b> 175	°C				
Diode - Inverter, Chopper							
I <sub>F</sub>	T <sub>s</sub> = 25 (70) °C	21 (17)	Α				
I <sub>FRM</sub>	$I_{FRM} = 2xI_{Fnom}, t_p = 1 \text{ ms}$	45	Α				
T <sub>j</sub>	·	-40 <b>+</b> 150	°C				
Rectifier							
$V_{RRM}$		1600	V				
I <sub>F</sub>	T <sub>s</sub> = 70 °C	28	Α				
I <sub>FSM</sub> / I <sub>TSM</sub>	$t_{\rm p} = 10 \text{ ms}$ , sin 180 °, $T_{\rm i} = 25 \text{ °C}$	220	Α				
I <sup>2</sup> t	$t_p = 10 \text{ ms}, \sin 180 ^{\circ}, T_i = 25 ^{\circ}\text{C}$	240	A²s				
T <sub>j</sub>		-40 <b>+</b> 175	°C				
T <sub>sol</sub>	Terminals, 10 s	260	°C				
T <sub>stg</sub>		-40 <b>+12</b> 5	°C				
V <sub>isol</sub>	AC, 1 min. / 1 s	2500 / 3000	V				

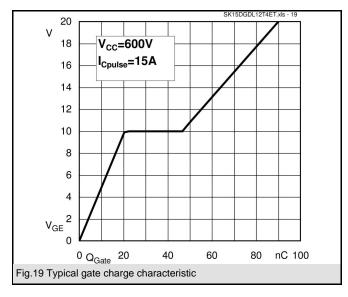
Characteristics		Ts = 25 °C, unless otherwise specified						
Symbol	Conditions	min.	typ.	max.	Units			
IGBT - Inverter								
$\begin{array}{c} V_{CEsat} \\ V_{GE(th)} \\ V_{CE(TO)} \\ r_T \\ C_{ies} \\ C_{oes} \\ C_{res} \\ R_{th(j-s)} \\ \end{array}$	$\begin{split} &I_{C} = 15 \text{ A, } T_{j} = 25 \text{ (150) °C} \\ &V_{GE} = V_{CE}, I_{C} = 0.5 \text{ mA} \\ &T_{j} = 25 \text{ °C (150) °C} \\ &T_{j} = 25 \text{ °C (150) °C} \\ &V_{CE} = 25 V_{GE} = 0 \text{ V, } f = 1 \text{ MHz} \\ &V_{CE} = 25 V_{GE} = 0 \text{ V, } f = 1 \text{ MHz} \\ &V_{CE} = 25 V_{GE} = 0 \text{ V, } f = 1 \text{ MHz} \\ &V_{CE} = 25 V_{GE} = 0 \text{ V, } f = 1 \text{ MHz} \\ &V_{CE} = 25 V_{GE} = 0 \text{ V, } f = 1 \text{ MHz} \\ &V_{CE} = 600 \text{ V, } V_{GE} = \pm 15 \text{ V} \end{split}$	5	5,8 1,1 (1) 50 (83,3) 0,9 0,08 0,055 1,65	2,05 (2,45) 6,5 1,3 (1,2)	V V V mΩ nF nF nF k/W			
$egin{aligned} \mathbf{t}_{ ext{d(off)}} \\ \mathbf{t_f} \\ \mathbf{E}_{ ext{on}} \\ \mathbf{E}_{ ext{off}} \end{aligned}$	$I_C$ = 15 A, $T_j$ = 150 °C $R_{Gon}$ = $R_{Goff}$ = 16 $\Omega$ inductive load		273 85 0,82 1,52		ns ns mJ mJ			
Diode - Inverter,Chopper								
r <sub>T</sub>	$I_F = 15 \text{ A}, T_j = 25(150) ^{\circ}\text{C}$ $T_j = 25 ^{\circ}\text{C} (150) ^{\circ}\text{C}$ $T_j = 25 ^{\circ}\text{C} (150) ^{\circ}\text{C}$ per diode		1,3 (0,9) 72 (102,7)	2,71 (2,77) 1,5 (1,1) 80,6 (111,3)	V V mΩ			
R <sub>th(j-s)</sub>	•		2,34					
I <sub>RRM</sub> Q <sub>rr</sub> E <sub>rr</sub>	under following conditions $I_F = 15 \text{ A}, V_R = V$ $V_{GE} = 0 \text{ V}, T_j = 150 ^{\circ}\text{C}$ $di_{F/dt} = 2750 \text{ A/}\mu\text{s}$		0,3 0,82		Α μC mJ			
Diode - Rectifier								
$V_{\text{F}} \\ V_{(\text{TO})} \\ r_{\text{T}} \\ R_{\text{th(j-s)}}$	$I_F = 15 \text{ A}, T_j = 25() ^{\circ}\text{C}$ $T_j = 150 ^{\circ}\text{C}$ $T_j = 150 ^{\circ}\text{C}$ per diode		1,1 0,9 20 2		V V mΩ K/W			
Temperatur sensor								
R <sub>ts</sub>	5 %, T <sub>r</sub> = 25 (100 ) °C		5000(493)		Ω			
Mechanical data								
w M <sub>s</sub>	Mounting torque	2,25	30	2,5	g Nm			

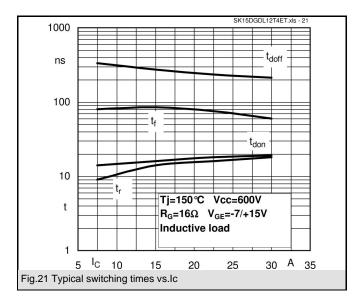


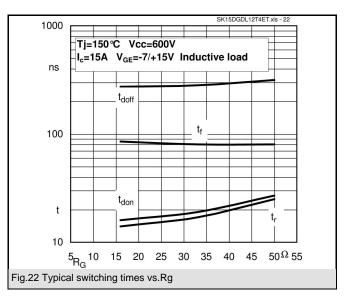


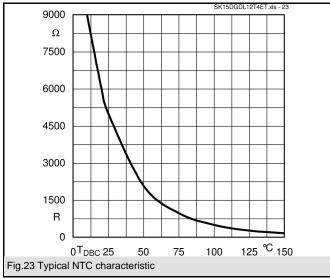


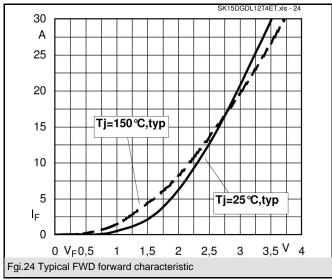




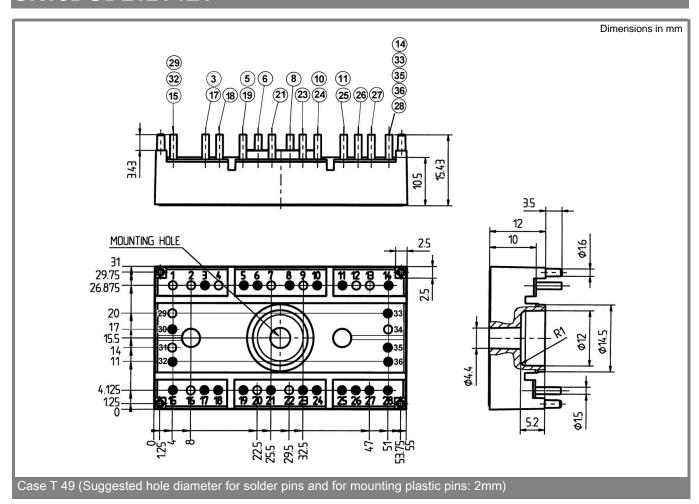


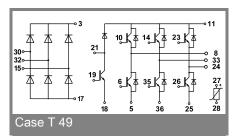






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This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

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<sup>\*</sup> The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of our personal.